## JQE Special Virtual Issue Dedicated to the 21<sup>st</sup> European Conference on Integrated Optics (ECIO)

THIS Special Issue is associated with the European Conference on Integrated Optics (ECIO), held on April 24–26, 2019, in Ghent, Belgium. This conference was the 21<sup>st</sup> in a series that started in London in 1981. The conference, hosted by Ghent University, was attended by about 240 participants. The conference was launched by the keynote speakers, Dr. Chris Doerr of Acacia Communications and Dr. Mark Thompson of the University of Bristol, who presented recent developments on photonic integrated components and circuits for coherent communications and quantum computing, respectively. The conference boasted 27 excellent invited speakers, covering diverse subjects in the booming field of photonic integration, along with 44 regular oral papers and 71 poster presentations.

The oral presenters of the conference were given the opportunity to submit papers for this special issue. As a result, this Special Issue now contains 15 papers that cover a diverse range of subjects in the field. Due to varied submission and review timeline, they appeared in different published journal issues, as shown in the Appendix. Most papers focus on basic components and circuits, based on both mainstream material platforms such as silicon-on-insulator, silicon nitride, and indium phosphide as well as on more specialized materials such as rare earth doped oxides. Noteworthy are the papers with focus on InP-membrane devices exploiting high-index-contrast concepts, the paper on MEMS approaches in silicon photonics, particularly for low-power reconfigurable circuits, and the paper on the use of new approaches for heterogeneous integration of InP on silicon by means of micro-transfer-printing.

The guest editors are thankful to the Editor-in-Chief Prof. Hon Ki Tsang, for providing the opportunity to dedicate this special issue to ECIO2019, to all authors and reviewers, and to the IEEE Photonics Society staff for supporting and managing the entire work flow.

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## APPENDIX Related Work

- J. C. Norman *et al.*, "The importance of p-doping for quantum dot laser on silicon performance," *IEEE J. Quantum Electron.*, vol. 55, no. 6, pp. 1–11, Dec. 2019.
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- Z. Wang *et al.*, "Optical frequency comb generation using CMOS compatible cascaded Mach–Zehnder modulators," *IEEE J. Quantum Electron.*, vol. 55, no. 6, pp. 1–6, Oct. 2019, doi: 10.1109/JQE.2019. 2948152.
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- N. Quack *et al.*, "MEMS-enabled silicon photonic integrated devices and circuits," *IEEE J. Quantum Electron.*, vol. 56, no. 1, pp. 1–10, Feb. 2020, doi: 10.1109/jqe.2019.2946841.
- 11) J. J. G. M. Van Der Tol, Y. Jiao, J. P. Van Engelen, V. Pogoretskiy, A. A. Kashi, and K. Williams, "InP membrane on silicon (IMOS) photonics," *IEEE J. Quantum Electron.*, vol. 56, no. 1, pp. 1–7, Feb. 2020, doi: 10.1109/jqe.2019.2953296.
- 12) D. Benedikovic *et al.*, "Comprehensive study on chip-integrated germanium pin photodetectors for energy-efficient silicon interconnects," *IEEE J. Quantum Electron.*, vol. 56, no. 1, pp. 1–9, Feb. 2020, doi: 10.1109/jqe.2019.2954355.
- 13) A. Ruiz-Caridad *et al.*, "Erbium-doped Yttria-stabilized Zirconia thin layers for photonic applications," *IEEE J. Quantum Electron.*, vol. 56, no. 2, pp. 1–7, Apr. 2020, doi: 10.1109/jqe.2019. 2955943.
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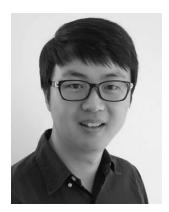


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